

TPS61169 采用 PWM 控制的 38V 高电流 升压 WLED 驱动器

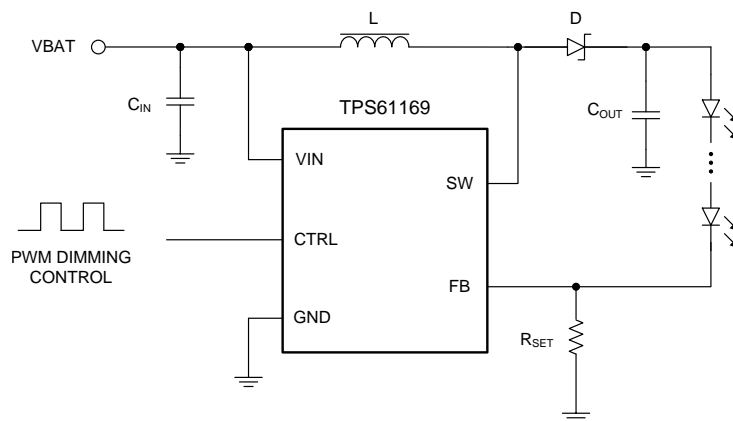
1 特性

- 2.7V 至 5.5V 输入电压
- 集成 40V、1.8A 金属氧化物半导体场效应晶体管 (MOSFET)
- 高达 38V 的 LED 串驱动电压
- 1.2A 开关电流下限
- 1.2MHz 开关频率
- 204mV 基准电压
- 内部补偿
- PWM 亮度控制
- LED 开路保护
- 欠压保护
- 内置软启动
- 热关断
- 效率高达 90%

2 应用

- 智能手机背光照明
- 平板电脑背光照明
- PDA、掌上电脑、GPS 接收器
- 便携式媒体播放器，便携式电视
- 针对小尺寸媒体播放器的白色 LED 背光照明

4 简化电路原理图



3 说明

TPS61169 是一款升压转换器，配有额定电压为 40V 的集成开关场效应晶体管 (FET)，可驱动 LED 串。该升压转换器内部具有一个 40V、1.8A 金属氧化物半导体场效应晶体管 (MOSFET)，电流下限为 1.2A，可针对小型或大型面板背光照明驱动单个 LED 或 LED 串。默认的白色 LED 电流通过外部传感器电阻 R_{SET} 设定，反馈电压稳压至 204mV，如[简化电路原理图](#)所示。运行期间，LED 电流可通过施加到 CTRL 引脚上的脉宽调制 (PWM) 信号加以控制，该信号的占空比决定反馈基准电压。TPS61169 不会突发 LED 电流，因此不会在输出电容器上产生可闻噪声。为提供最佳保护，该器件集成了 LED 开路保护特性，该特性会在 LED 开路状态下禁用 TPS61169，以防止输出电压超过 IC 最大绝对额定电压。

TPS61169 采用节省空间的 5 引脚 SC70 封装。

器件信息⁽¹⁾

器件型号	封装	封装尺寸 (标称值)
TPS61169	SOT (5)	2.00mm x 1.25mm

(1) 要了解所有可用封装，请见数据表末尾的可订购产品附录。



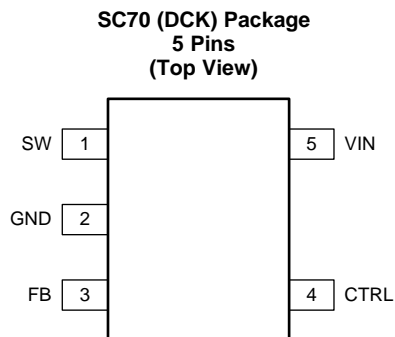
目录

1	特性	1	8.3	Feature Description	8
2	应用	1	8.4	Device Functional Modes.....	10
3	说明	1	9	Application and Implementation	11
4	简化电路原理图	1	9.1	Application Information.....	11
5	修订历史记录	2	9.2	Typical Application	11
6	Pin Configuration and Functions	3	9.3	TPS61169 Application Curves	13
7	Specifications.....	4	10	Power Supply Recommendations	16
7.1	Absolute Maximum Ratings	4	11	Layout.....	16
7.2	Handling Ratings	4	11.1	Layout Guidelines	16
7.3	Recommended Operating Conditions.....	4	11.2	Layout Example	16
7.4	Thermal Information	5	12	器件和文档支持	17
7.5	Electrical Characteristics.....	5	12.1	第三方产品免责声明.....	17
7.6	Typical Characteristics.....	6	12.2	商标.....	17
8	Detailed Description	7	12.3	静电放电警告.....	17
8.1	Overview	7	12.4	术语表	17
8.2	Functional Block Diagram	8	13	机械封装和可订购信息	17

5 修订历史记录

日期	修订版本	注释
2014 年 10 月	*	最初发布版本

6 Pin Configuration and Functions



Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
SW	1	I	Drain connection of the internal power FET.
GND	2	O	Ground
FB	3	I	Feedback pin for current. Connect the sense resistor from FB to GND.
CTRL	4	I	PWM dimming signal input
VIN	5	I	Supply input pin

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		MIN	MAX	UNIT
Voltage ⁽²⁾	VIN, CTRL, PWM, FB	-0.3	7	V
	SW	-0.3	40	
P _D	Continuous power dissipation	See Thermal Information Table		
T _J	Operating junction temperature	-40	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground terminal.

7.2 Handling Ratings

		MIN	MAX	UNIT	
T _{stg}	Storage temperature range	-65	150	°C	
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	-2000	2000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	-500	500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V _{IN}	Input voltage	2.7		5.5	V
V _{OUT}	Output voltage	V _{IN}		38	V
L	Inductor	4.7		10	μH
C _I	Input capacitor	1			μF
C _O	Output capacitor	1		10	μF
F _{PWM}	PWM dimming signal frequency	5		100	kHz
D _{PWM}	PWM dimming signal duty cycle	1%		100%	
T _J	Operating junction temperature	-40		125	°C

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TPS61169	UNIT
		DCK	
		(5 PINS)	
R _{θJA}	Junction-to-ambient thermal resistance ⁽²⁾	263.8	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance ⁽³⁾	76.1	
R _{θJB}	Junction-to-board thermal resistance ⁽⁴⁾	51.4	
ψ _{JT}	Junction-to-top characterization parameter ⁽⁵⁾	1.1	
ψ _{JB}	Junction-to-board characterization parameter ⁽⁶⁾	50.7	

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).
- (2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
- (3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
- (4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
- (5) The junction-to-top characterization parameter, ψ_{JT}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining R_{θJA}, using a procedure described in JESD51-2a (sections 6 and 7).
- (6) The junction-to-board characterization parameter, ψ_{JB}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining R_{θJA}, using a procedure described in JESD51-2a (sections 6 and 7).

7.5 Electrical Characteristics

Over operating free-air temperature range, V_{IN} = 3.6 V, CTRL = V_{IN} (unless otherwise specified).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER SUPPLY						
V _{IN}	Input voltage range		2.7		5.5	V
V _{VIN_UVLO}	Undervoltage lockout threshold	V _{IN} falling V _{IN} rising		2	2.3 2.6	V
V _{VIN_HYS}	V _{IN} UVLO hysteresis			200		mV
I _{Q_VIN}	Operating quiescent current into V _{IN}	Device enable, switching 1.2 MHz and no load,		0.3	0.45	mA
I _{SD}	Shutdown current	CTRL = GND		1	2	μA
CONTROL LOGIC AND TIMING						
V _H	CTRL Logic high voltage		1.2			V
V _L	CTRL Logic Low voltage				0.4	V
R _{PD}	CTRL pin internal pull-down resistor			300		KΩ
t _{SD}	CTRL logic low time to shutdown	CTRL high to low	2.5			ms
VOLTAGE AND CURRENT REGULATION						
V _{REF}	Voltage feedback regulation voltage	Duty = 100%, T _A ≥ 25°C	188	204	220	mV
I _{FB}	FB pin bias current	V _{FB} = 204 mV			2.5	μA
t _{REF}	V _{REF} filter time constant			1		ms
POWER SWITCH						
R _{DS(ON)}	N-channel MOSFET on-resistance			0.35	0.7	Ω
I _{LN_NFET}	N-channel leakage current	V _{SW} = 35 V			1	μA
SWITCHING FREQUENCY						
f _{SW}	Switching frequency	V _{IN} = 3 V	0.75	1.2	1.5	MHz
PROTECTION AND SOFT START						
I _{LIM}	Switching MOSFET current limit	D = D _{MAX} , T _A ≤ 85°C	1.2	1.8	2.4	A
I _{LIM_Start}	Switching MOSFET start-up current limit	T _A ≤ 85°C		0.72		
t _{Half_LIM}	Time step for half current limit			6.5		ms

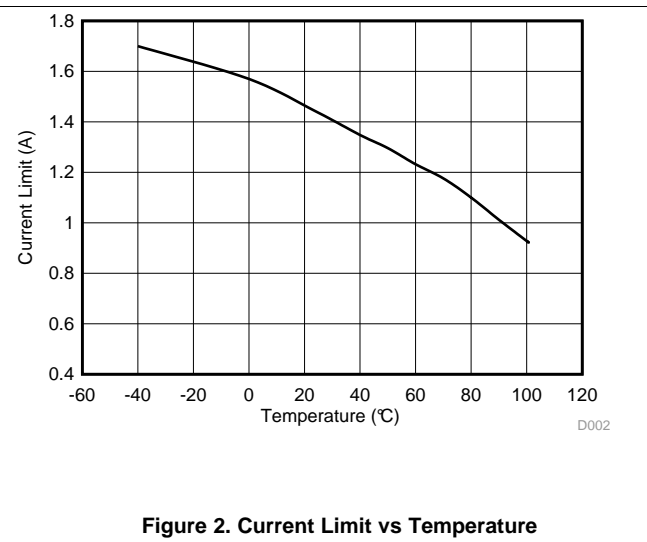
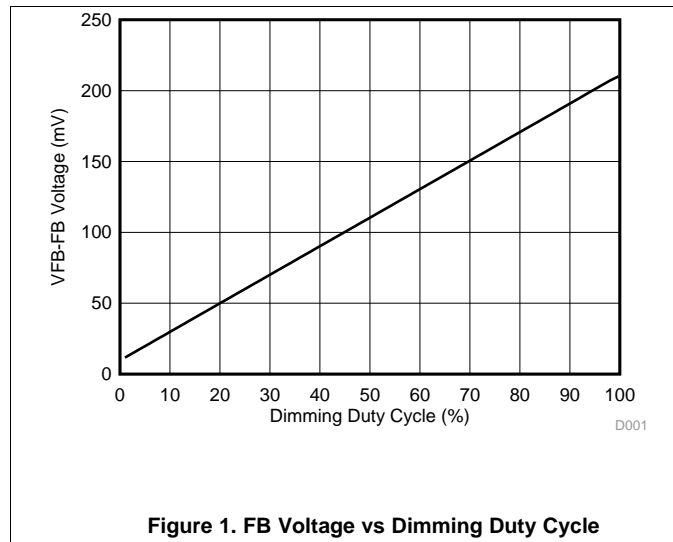
Electrical Characteristics (continued)

Over operating free-air temperature range, $V_{IN} = 3.6\text{ V}$, $CTRL = V_{IN}$ (unless otherwise specified).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{OVP_SW}	Output voltage overvoltage threshold		36	37.5	39	V
THERMAL SHUTDOWN						
$T_{shutdown}$	Thermal shutdown threshold			160		°C
T_{hys}	Thermal shutdown hysteresis			15		°C

7.6 Typical Characteristics

At $T_A = 25^\circ\text{C}$, unless otherwise noted.



8 Detailed Description

8.1 Overview

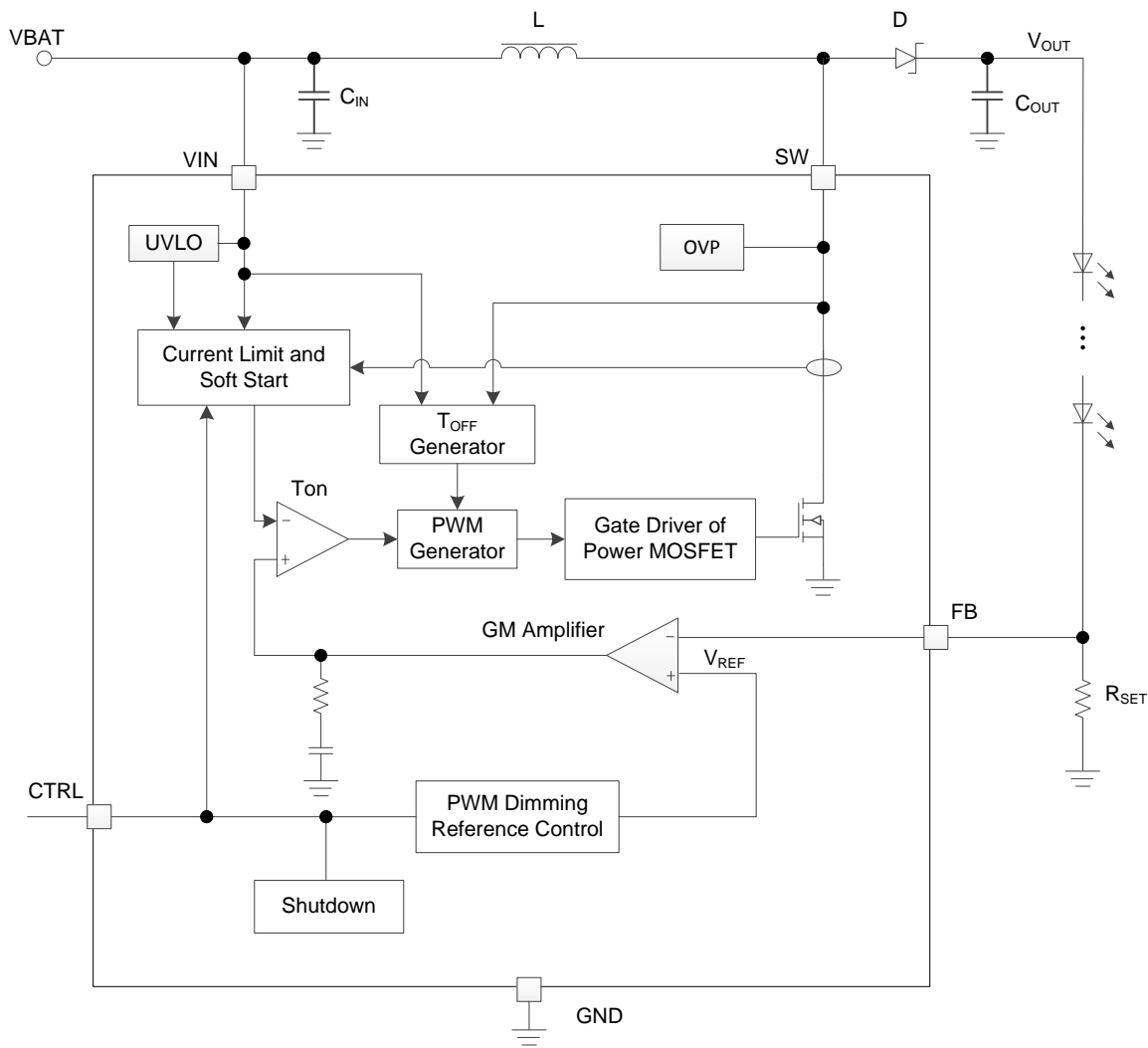
The TPS61169 is a high-efficiency, high-output voltage boost converter in small package size. The device integrates 40-V/1.8-A switch FET and is designed for output voltage up to 39 V with a switch peak current limit of 1.2 A minimum. Its large driving capability can drive single or parallel LED strings for small to large size panel backlighting.

The TPS61169 operates in a current mode scheme with quasi-constant frequency. It is internally compensated for maximum flexibility and stability. The switching frequency is 1.2 MHz, and the minimum input voltage is 2.7 V. During the on-time, the current rises into the inductor. When the current reaches a threshold value set by the internal GM amplifier, the power switch MOSFET is turned off. The polarity of the inductor changes and forward biases the schottky diode which lets the current flow towards the output of the boost converter. The off-time is fixed for a certain V_{IN} and V_{OUT} , and therefore maintains the same frequency when varying these parameters.

However, for different output loads, the frequency slightly changes due to the voltage drop across the $R_{DS(ON)}$ of the power switch MOSFET, this has an effect on the voltage across the inductor and thus on t_{ON} (t_{OFF} remains fixed). The fixed off-time maintains a quasi-fixed frequency that provides better stability for the system over a wider range of input and output voltages than conventional boost converters. The TPS61169 topology has also the benefits of providing very good load and line regulations, and excellent line and load transient responses.

The feedback loop regulates the FB pin to a low reference voltage (204 mV typical), reducing the power dissipation in the current sense resistor.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Soft Start-Up

Soft-start circuitry is integrated into the IC to avoid high inrush current spike during start-up. After the device is enabled, the GM amplifier output voltage ramps up very slowly, which ensures that the output voltage rises slowly to reduce the input current. During this period, the switch current limit is set to 0.72 A. After around 6.5 ms, the switch current limit changes back to I_{LIM} , and the FB pin voltage ramps up to the reference voltage slowly. These features ensure the smooth start-up and minimize the inrush current. See [Figure 12](#) for a typical example.

8.3.2 Open LED Protection

Open LED protection circuitry prevents IC damage as the result of white LED disconnection. The TPS61169 monitors the voltage at the SW pin and FB pin during each switching cycle. The circuitry turns off the switch FET and shuts down the IC when both of the following conditions persist for 3 switching cycles: (1) the SW voltage exceeds the VOVP threshold, and (2) the FB voltage is less than 30 mV. As the result, the output voltage falls to the level of the input supply. The device remains in shutdown mode until it is enabled by toggling the CTRL pin.

Feature Description (continued)

8.3.3 Shutdown

The TPS61169 enters shutdown mode when the CTRL voltage is logic low for more than 2.5 ms. During shutdown, the input supply current for the device is less than 2 μ A (max). Although the internal switch FET does not switch in shutdown, there is still a DC current path between the input and the LEDs through the inductor and Schottky diode. The minimum forward voltage of the LED array must exceed the maximum input voltage to ensure that the LEDs remain off in shutdown.

8.3.4 Current Program

The FB voltage is regulated by a low 204-mV reference voltage. The LED current is programmed externally using a current-sense resistor in series with the LED string(s). The value of the R_{SET} is calculated using:

$$I_{LED} = \frac{V_{FB}}{R_{SET}}$$

where

- I_{LED} = total output current of LED string(s)
- V_{FB} = regulated voltage of FB pin
- R_{SET} = current sense resistor

(1)

The output current tolerance depends on the FB accuracy and the current sensor resistor accuracy.

8.3.5 LED Brightness Dimming

The TPS61169 receives PWM dimming signal at CTRL pin to control the total output current. When the CTRL pin is constantly high, the FB voltage is regulated to 204 mV typically. When the duty cycle of the input PWM signal is low, the regulation voltage at FB pin is reduced, and the total output current is reduced; therefore, it achieves LED brightness dimming. The relationship between the duty cycle and FB regulation voltage is given by:

$$V_{FB} = \text{Duty} \times 204 \text{ mV}$$

where

- Duty = Duty cycle of the PWM signal
- 204 mV = internal reference voltage

(2)

Thus, the user can easily control the WLED brightness by controlling the duty cycle of the PWM signal.

As shown in [Figure 3](#), the IC chops up the internal 204-mV reference voltage at the duty cycle of the PWM signal. The pulse signal is then filtered by an internal low-pass filter. The output of the filter is connected to the GM amplifier as the reference voltage for the FB pin regulation. Therefore, although a PWM signal is used for brightness dimming, only the WLED DC current is modulated, which is often referred as analog dimming. This eliminates the audible noise which often occurs when the LED current is pulsed in replica of the frequency and duty cycle of PWM control. Unlike other methods which filter the PWM signal for analog dimming, TPS61169 regulation voltage is independent of the PWM logic voltage level which often has large variations.

For optimum performance, use the PWM dimming frequency in the range of 5 kHz to 100 kHz. If the PWM frequency is lower than 5 kHz, it is out of the low pass filter's filter range, the FB regulation voltage ripple becomes large, causing large output ripple and may generate audible noise.

Feature Description (continued)

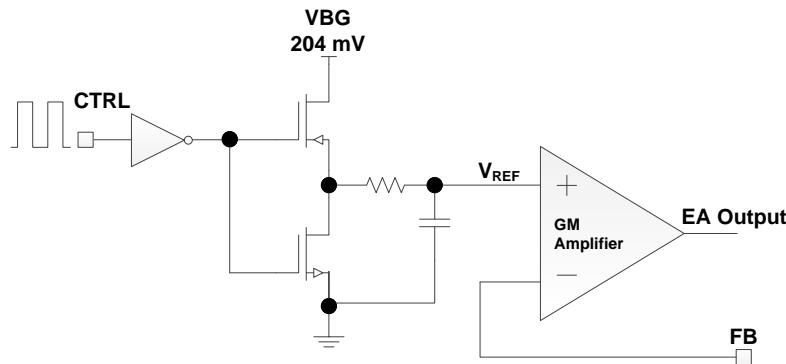


Figure 3. Programmable FB Voltage Using PWM Signal

8.3.6 Undervoltage Lockout

An undervoltage lockout prevents operation of the device at input voltages below typical 2 V. When the input voltage is below the undervoltage threshold, the device is shut down, and the internal switch FET is turned off. If the input voltage rises by undervoltage lockout hysteresis, the IC restarts.

8.3.7 Thermal Foldback and Thermal Shutdown

When TPS61169 drives heavy load for large size panel applications, the power dissipation increases a lot and the device junction temperature may reach a very high value, affecting the device function and reliability. In order to lower the thermal stress, the TPS61169 features a thermal foldback function. When the junction temperature is higher than 100°C, the switch current limit I_{LIM} is reduced automatically as [Figure 2](#) shows. This thermal foldback mechanism controls the power dissipation and keeps the junction temperature from rising to a very high value. If the typical junction temperature of 160°C is exceeded, an internal thermal shutdown turns off the device. The device is released from shutdown automatically when the junction temperature decreases by 15°C.

8.4 Device Functional Modes

8.4.1 Operation With CTRL

The enable rising edge threshold voltage is 1.2 V. With the CTRL terminal is held below that voltage the device is disabled and switching is inhibited. The IC quiescent current is reduced in this state. When input voltage is above the UVLO threshold, and the CTRL terminal voltage is increased above the rising edge threshold, the device becomes active. Switching enables, and the soft-start sequence initiates.

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TPS61169 device is a step-up DC-DC converter which can drive single or parallel LED strings for small- to large-size panel backlighting. This section includes a design procedure ([Detailed Design Procedure](#)) to select component values for the TPS61169 typical application ([Figure 4](#)).

9.2 Typical Application

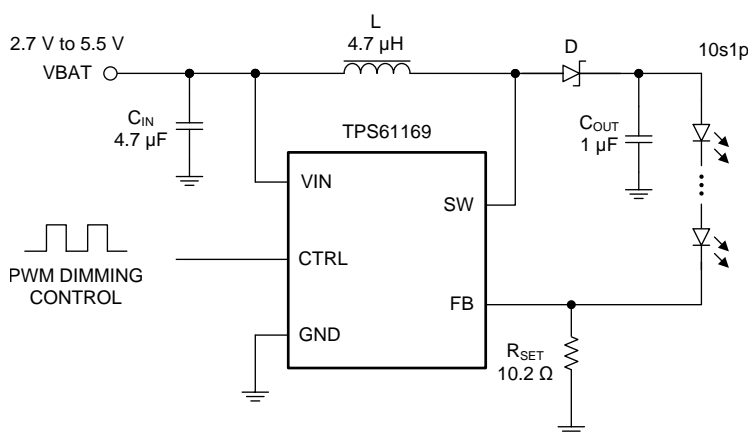


Figure 4. TPS61169 2.7-V to 5.5-V Input, 10 LEDs in Series Output Converter

9.2.1 Design Requirements

For this design example, use the parameters listed in [Table 1](#) as the input parameters.

Table 1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	2.7 V to 5.5 V
Output, LED number in a string	10
Output, LED string number	1
Output, LED current per string	20 mA

9.2.2 Detailed Design Procedure

9.2.2.1 Inductor Selection

The selection of the inductor affects power efficiency, steady state operation as well as transient behavior and loop stability. These factors make it the most important component in power regulator design. There are three important inductor specifications, inductor value, DC resistance and saturation current. Considering inductor value alone is not enough. The inductor value determines the inductor ripple current. Choose an inductor that can handle the necessary peak current without saturating. Follow [Equation 3](#) to [Equation 4](#) to calculate the inductor's peak current. To calculate the current in the worst case, use the minimum input voltage, maximum output voltage and maximum load current of application. In a boost regulator, the input DC current can be calculated as [Equation 3](#).

$$I_{L(DC)} = \frac{V_{OUT} \times I_{OUT}}{V_{IN} \times \eta}$$

where

- V_{OUT} = boost output voltage
 - I_{OUT} = boost output current
 - V_{IN} = boost input voltage
 - η = power conversion efficiency
- (3)

The inductor current peak to peak ripple can be calculated as [Equation 4](#).

$$\Delta I_{L(P-P)} = \frac{1}{L \times \left(\frac{1}{V_{OUT} - V_{IN}} + \frac{1}{V_{IN}} \right) \times F_S}$$

where

- $\Delta I_{L(P-P)}$ = inductor peak-to-peak ripple
 - L = inductor value
 - F_S = boost switching frequency
 - V_{OUT} = boost output voltage
 - V_{IN} = boost input voltage
- (4)

Therefore, the peak current $I_{L(P)}$ seen by the inductor is calculated with [Equation 5](#).

$$I_{L(P)} = I_{L(DC)} + \frac{\Delta I_{L(P-P)}}{2}$$
(5)

Inductor values can have $\pm 20\%$ tolerance with no current bias. When the inductor current approaches saturation level, its inductance can decrease 20% to 35% from the 0-A value depending on how the inductor vendor defines saturation current. Using an inductor with a smaller inductance value forces discontinuous PWM when the inductor current ramps down to zero before the end of each switching cycle. This reduces the boost converter's maximum output current, causes large input voltage ripple and reduces efficiency. Large inductance value provides much more output current and higher conversion efficiency. For these reasons, a 4.7- μH to 10- μH inductor value range is recommended, and 4.7- μH inductor is recommended for higher than 5-V input voltage by considering inductor peak current and loop stability. [Table 2](#) lists the recommended inductor for the TPS61169.

Table 2. Recommended Inductors for TPS61169

PART NUMBER	L (μH)	DCR MAX (m Ω)	SATURATION CURRENT (A)	SIZE (L x W x H mm)	VENDOR
LPS4018-472ML	4.7	125	1.9	4 x 4 x 1.8	Coilcraft
LPS4018-103ML	10	200	1.3	4 x 4 x 1.8	Coilcraft
PCMB051H-4R7M	4.7	85	4	5.4 x 5.2 x 1.8	Cyntec
PCMB051H-100M	10	155	3	5.4 x 5.2x 1.8	Cyntec

9.2.2.2 Schottky Diode Selection

The TPS61169 demands a low forward voltage, high-speed and low capacitance Schottky diode for optimum efficiency. Ensure that the diode average and peak current rating exceeds the average output current and peak inductor current. In addition, the diode reverse breakdown voltage must exceed the open LED protection voltage. ONSem NSR0240 is recommended for the TPS61169.

9.2.2.3 Output Capacitor Selection

The output capacitor is mainly selected to meet the requirement for the output ripple and loop stability. This ripple voltage is related to capacitor capacitance and its equivalent series resistance (ESR). Assuming a capacitor with zero ESR, the minimum capacitance needed for a given ripple can be calculated with [Equation 6](#):

$$C_{OUT} = \frac{(V_{OUT} - V_{IN}) \times I_{OUT}}{V_{OUT} \times F_S \times V_{ripple}}$$

where

- V_{ripple} = peak-to-peak output ripple (6)

The additional part of the ripple caused by ESR is calculated using: $V_{\text{ripple_ESR}} = I_{\text{OUT}} \times R_{\text{ESR}}$

Due to its low ESR, $V_{\text{ripple_ESR}}$ could be neglected for ceramic capacitors, a 1- μF to 4.7- μF capacitor is recommended for typical application.

9.2.2.4 LED Current Set Resistor

The LED current set resistor can be calculated by Equation 1.

9.2.2.5 Thermal Considerations

The allowable IC junction temperature should be considered under normal operating conditions. This restriction limits the power dissipation of the TPS61169. The allowable power dissipation for the device can be determined by Equation 7:

$$P_D = \frac{T_J - T_A}{R_{\theta JA}}$$

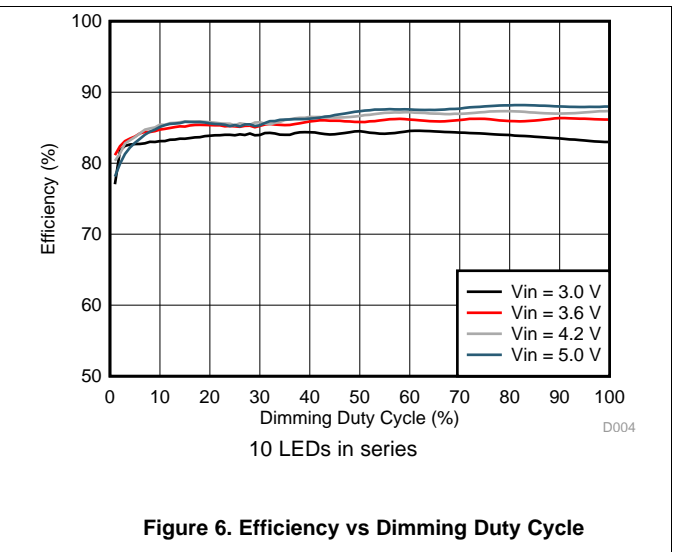
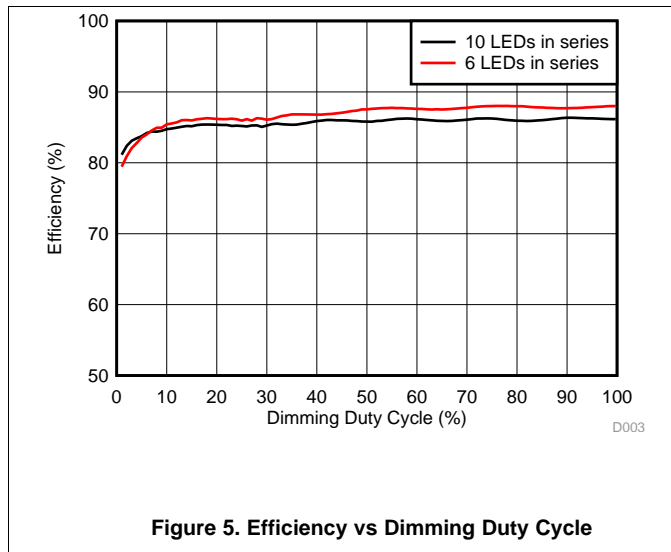
where

- T_J is allowable junction temperature given in recommended operating conditions
- T_A is the ambient temperature for the application
- $R_{\theta JA}$ is the thermal resistance junction-to-ambient given in Power Dissipation Table (7)

The TPS61169 device also features a thermal foldback function to reduce the thermal stress automatically.

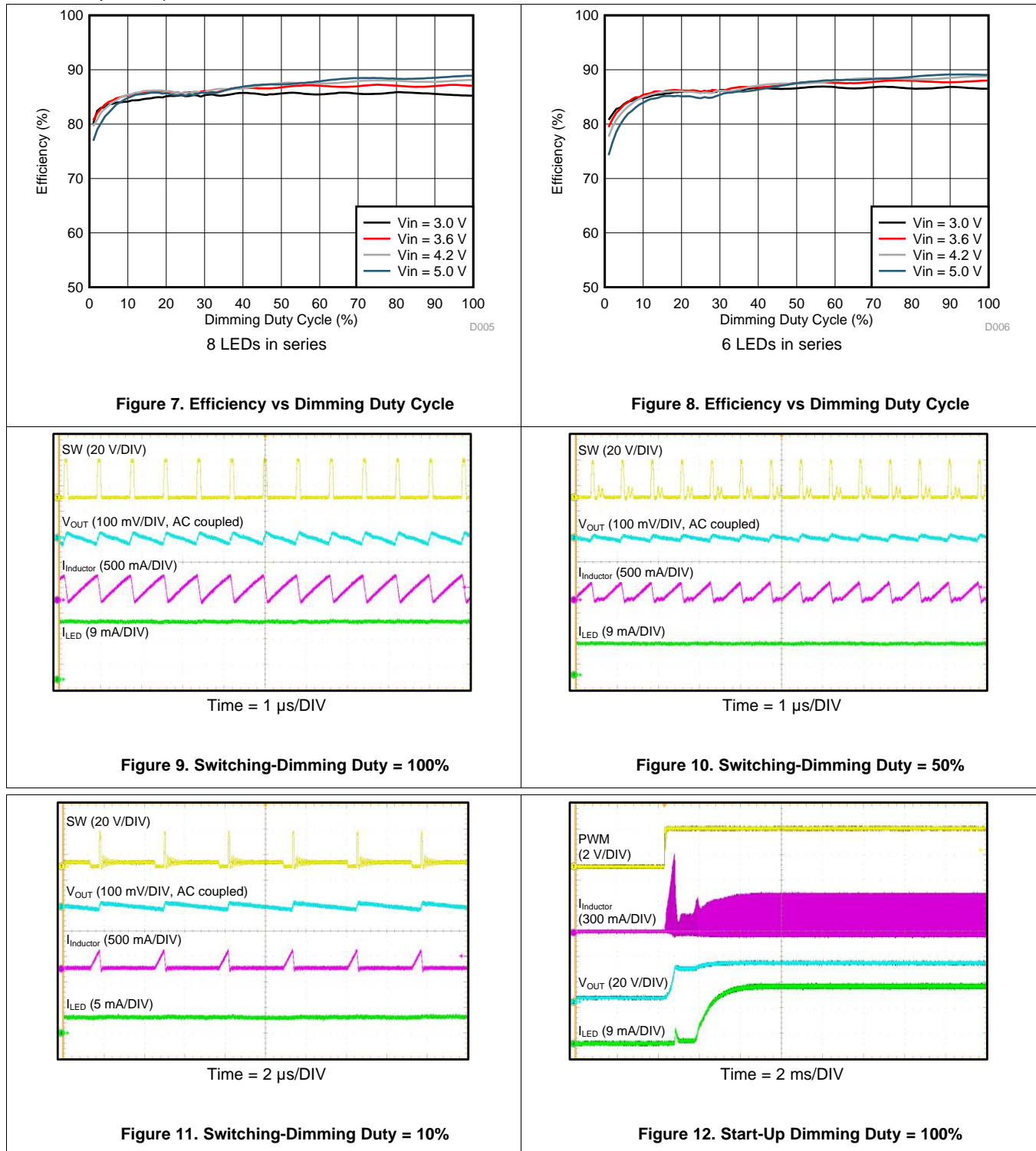
9.3 TPS61169 Application Curves

Typical application condition is as in Figure 4, $V_{\text{IN}} = 3.6 \text{ V}$, $R_{\text{SET}} = 10.2 \Omega$, $L = 4.7 \mu\text{H}$, $C_{\text{OUT}} = 1 \mu\text{F}$, 10 LEDs in series (unless otherwise specified).



TPS61169 Application Curves (continued)

Typical application condition is as in Figure 4, $V_{IN} = 3.6\text{ V}$, $R_{SET} = 10.2\ \Omega$, $L = 4.7\ \mu\text{H}$, $C_{OUT} = 1\ \mu\text{F}$, 10 LEDs in series (unless otherwise specified).



TPS61169 Application Curves (continued)

Typical application condition is as in Figure 4, $V_{IN} = 3.6\text{ V}$, $R_{SET} = 10.2\ \Omega$, $L = 4.7\ \mu\text{H}$, $C_{OUT} = 1\ \mu\text{F}$, 10 LEDs in series (unless otherwise specified).

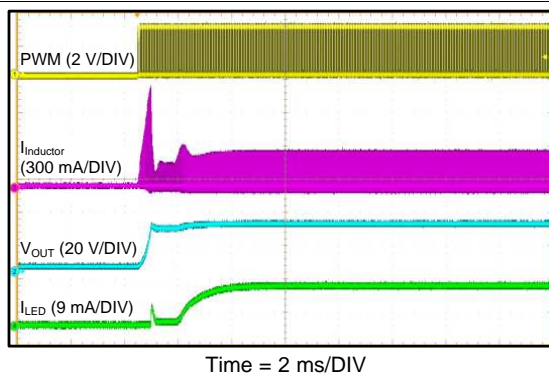


Figure 13. Start-Up Dimming Duty = 50%

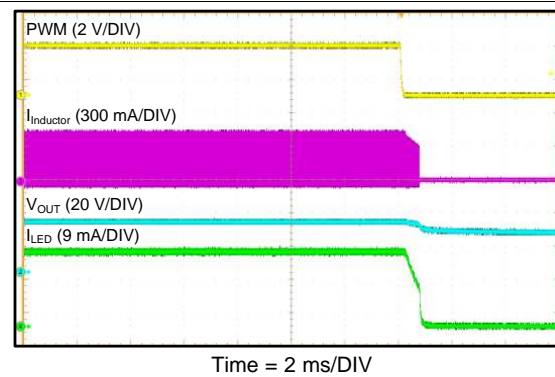


Figure 14. Shutdown Dimming Duty = 100%

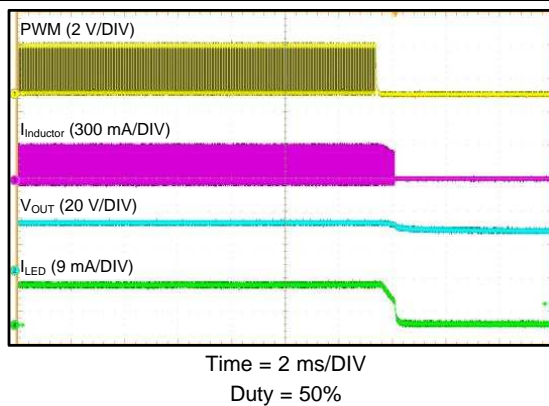


Figure 15. Shutdown Dimming

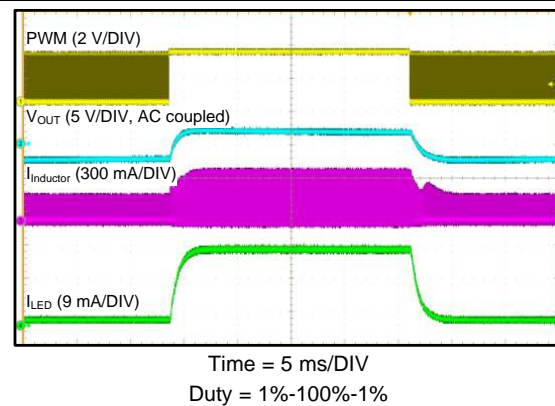


Figure 16. Dimming Transient-Dimming

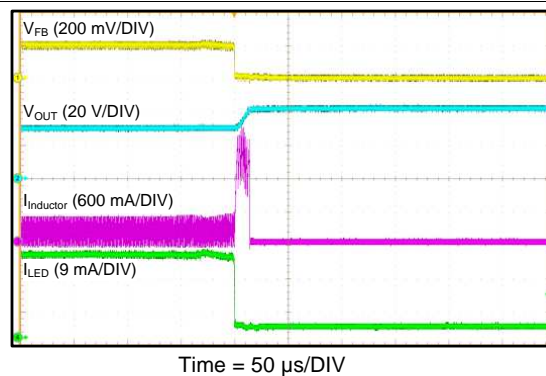


Figure 17. Open LED Protection

10 Power Supply Recommendations

The device is designed to operate from an input voltage supply range between 2.7 V and 5.5 V. This input supply must be well regulated. If the input supply is located more than a few inches from the TPS61169 device, additional bulk capacitance may be required in addition to the ceramic bypass capacitors.

11 Layout

11.1 Layout Guidelines

As for all switching power supplies, especially those high frequency and high current ones, layout is an important design step. If layout is not carefully done, the regulator could suffer from instability as well as noise problems. Therefore, use wide and short traces for high current paths. The input capacitor C_{IN} needs to be close to VIN pin and GND pin in order to reduce the input ripple seen by the IC. If possible choose higher capacitance value for it. The SW pin carries high current with fast rising and falling edge, therefore, the connection between the SW pin to the inductor should be kept as short and wide as possible. The output capacitor C_{OUT} should be put close to VOUT pin. It is also beneficial to have the ground of C_{OUT} close to the GND pin since there is large ground return current flowing between them. FB resistor should be put close to FB pin. When laying out signal ground, it is recommended to use short traces separated from power ground traces, and connect them together at a single point close to the GND pin.

11.2 Layout Example

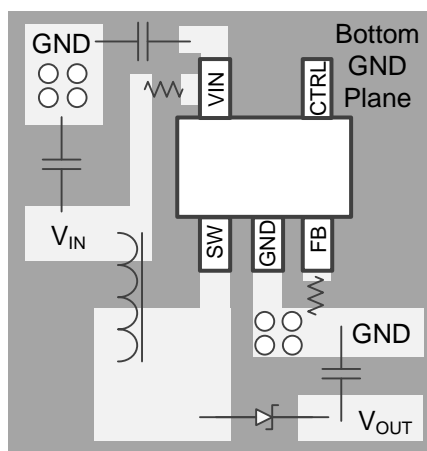


Figure 18. TPS61169 Board Layout

12 器件和文档支持

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12.4 术语表

[SLYZ022](#) — TI 术语表。

这份术语表列出并解释术语、首字母缩略词和定义。

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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS61169DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	SZL	Samples

(1) The marketing status values are defined as follows:

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TBD: The Pb-Free/Green conversion plan has not been defined.

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(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AA.

DCK (R-PDSO-G5)

PLASTIC SMALL OUTLINE



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 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

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